

95-2133

# 100413 Nc1

NWC Technical Memorandum 2514



# REDUCTION OF RETICLE REFLECTANCE

by

Henry Blazek

and

**Robert Hunt** 

Electromechanical Division

Engineering Department

March 1975

AD AO 63471

FILE COPY

100



Approved for public relase; distribution unlimited. This is not an official report of theNaval Weapons Center and is not to be used as authority for action.

Naval Weapons Center China Lake, California 93555

78 11 28 166

MAY	2	5	1978	
-----	---	---	------	--

		INMENT-INDUSTRY DATA EXC		V duer	
GEN	ERAL DOC	Type All Information - See Instru	ctions on Reverse		1 OF 1
DED95	-2133	2. COMPONENT/PART NAME PER Optical Devic			
Engineering		NOTIFIED	X NOT APPLICAB	S. DOCUMENT ISSUE (M. Mar ga 1975	
Reduction of	Reticle Reflectar	nce , /		GEN RPT	
NWC-TM-2514		N/A			
None	(UNPERANTS) ACCESS NO.	11. ENVIRONMENTAL EXPOSURE N/A			
	/A	13. MANUPACTURER PART NUMB N/A	*	14. INDUSTRY/GOVERNM	ENT STANDARD NUMBER
(12) <u>13</u>	PI OR CONTALENT OF	GIDEI	2		
	Relative reflectar a surface to that using near normal can be utilized to absorption. The e ment of a techniquing is dependent us that the minimum here reflectance should The objective is a rough reticle pate	of a perfectly incident radiat o reduce the rel efforts describe ue which emphasi upon surface rou RMS value of rou d be one-fifth t then narrowed to	smooth surfaction. There at ative reflect ad here were do zed the scatt ighness, and f ighness to obt the wavelength o the problem	e of the same are two mechani- ance: scatter irected toward ering mechani- an general one ain less than of the incide of producing	material Isms which ring and d the develop- sm. Scatter- may state 10% relative ent radiation.
10	Henry	Blazek	Robe	ert /H	ont
97	Technico	ul mem	015 [		
-					
			•		
		Es -		00.	1 C C .
		78	11	28	166
R	• Reticle Reflecta Surface Roughnes	ince; Electrogop	tic Guidance;	Reflectance;	
16. КЕТ WORDS POR MOEXIM 17. GOOLP REPRESENTATIVE М. Н. Sloan		ince; Electrogop	tic Guidance;	Reflectance;	Scattering;

# FOREWORD

This report describes a process whereby reticles fabricated on sapphire substrates have low reflectivity from both front and back. This work was funded in part by the AIM-9L program. Work was begun in Fiscal Year 1973. Since this report descusses preliminary findings that are subject to modification, it is released at the working level.

M. K. Pladson Head (Acting), Electromechanical Division Engineering Department 26 March 1975

ICESEIND IN	Rhite Bactions	
106	Par annual	āl .
nothernon Mothernon	811	
	and the file	
87	MER/EVAILABILITY OF	
87	AVAIL WILL WE WE	-
	ATAIL OLIVE BUD	5

NWC TM 2514, published by Code 531, 15 copies.

## REDUCTION OF RETICLE REFLECTANCE

#### OBJECTIVE

The objective of the effort reported here is to minimize the relative reflectance of reticles used in electro-optic guidance systems. Relative reflectance is defined as the ratio of observed reflectance of a surface to that of a perfectly smooth surface of the same material using near normal incident radiation. There are two mechanisms which can be utilized to reduce the relative reflectance: scattering and absorption. The efforts described here were directed toward the development of a technique which emphasized the scattering mechanism. Scattering is dependent upon surface roughness, and in general one may state that the minimum RMS value of . roughness to obtain less than 10% relative reflectance should be one-fifth the wavelength of the incident radiation.<sup>1</sup> The objective is then narrowed to the problem of producing a sufficiently rough reticle pattern on a smooth transmitting substrate.

#### EXPERIMENTAL OBJECTIVES

In the evaluation of each of the proposed scattering techniques, it is necessary to take into consideration the following conditions:

1. Any reduction must extend from the visible out to 4.5 microns.

2. Assuming 4.0 microns as the primary wavelength and extrapolating from reference 1, the surface roughness desired must be 1 micron RMS.

3. Only the opaque portions of the reticle must be roughened.

4. Both the front surface and the interface boundary must be reduced in relative reflectance.

5. Edge resolution of the reticle pattern must be held to . 0.25 micron (0.01 mil).

<sup>1</sup>H. E. Bennett, J. Opt. Soc. Amer., Vol 53, No. 12 (December 1963), pp. 1389-94.

out a stand a state.

### APPROACH

Consider Figure 1 which illustrates two aspects of reflection that are the basis for the need to reduce the reflectance of the reticle pattern. These reflected rays eventually reach the detector, producing optical noise and hence reducing the signal-to-noise ratio of the detection system. The front surface reflections (Ray A) can be dealt with in a straightforward manner. One need only consider those techniques that produce a rough front surface in the opaque reticle areas. The following techniques were evaluated with the experimental objectives as constraints:

- 1. grinding
- 2. sandblasting
- 3. ultrasonic grinding
- 4. laser blasting
- 5. chemical frosting
- 6. diffusion-etching
- 7. controlled film structure
  - a. sputter deposition
  - b. heat treatment

The best results were obtained by using sputtered films. The front surface roughness of these films is a function of the sputtering parameters and can be easily reproduced.<sup>2</sup> Figures 2 through 5 show the reduction of relative reflectance for the front surface of various sputtered films.

The second reflection (Ray B in Figure 1), described as the interface reflection since it occurs at the interface of the transmitting substrate and the reflecting film of the reticle pattern is a more difficult case, particularly when those techniques which preroughen the entire substrate are unusable. A solution to the interface reflection was developed when it was found that a reticle pattern photo etched in an aluminum film would produce a rough surface when properly heat-treated. In this technique the aluminum is oxidized to form the transparent aluminum oxide and hence must be recoated with a film to make the roughened areas opaque. The details of this technique are illustrated in Figures 6 and 7.

<sup>2</sup>Naval Weapons Center. Sputter Deposition of Zirconium and Titanium Onto Metal Cubes, by H. Blazek, C. Cutsinger, and G. Turner. China Lake, Calif., NWC, September 1972. (IDP 3391, publication UNCLASSIFIED.)

in motive statist with the set

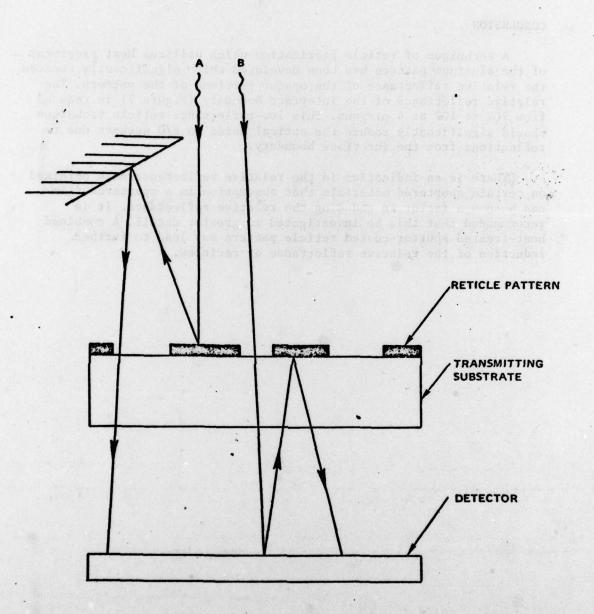
#### CONCLUSION

A technique of reticle fabrication which utilizes heat treatment of the aluminum pattern has been developed which significantly reduces the relative reflectance of the opaque portions of the pattern. The relative reflectance of the interface boundary (Figure 7) is reduced from 70% to 10% at 4 microns. This low-reflectance reticle technique should significantly reduce the optical noise in E/O seekers due to reflections from the interface boundary.

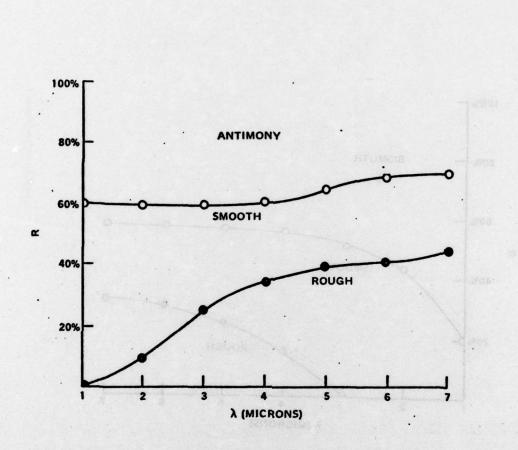
There is an indication in the relative reflectance data obtained on certain sputtered materials that absorption in a sputtered film can become a factor in reducing the relative reflectance. It is recommended that this be investigated in greater detail. A combined heat-treated sputter-coated reticle pattern may lead to further reduction of the relative reflectance of reticles.

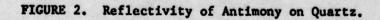
STUDE 1. Reilantions Contraction

· .

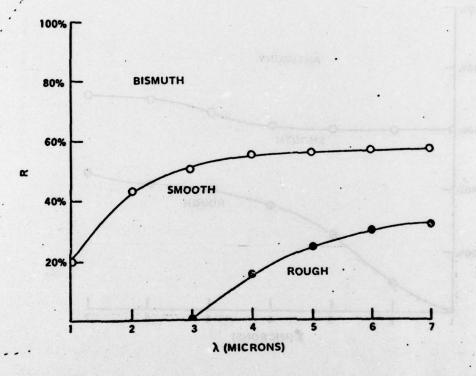


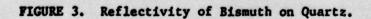
# FIGURE 1. Reflections Contributing to Optical Noise.

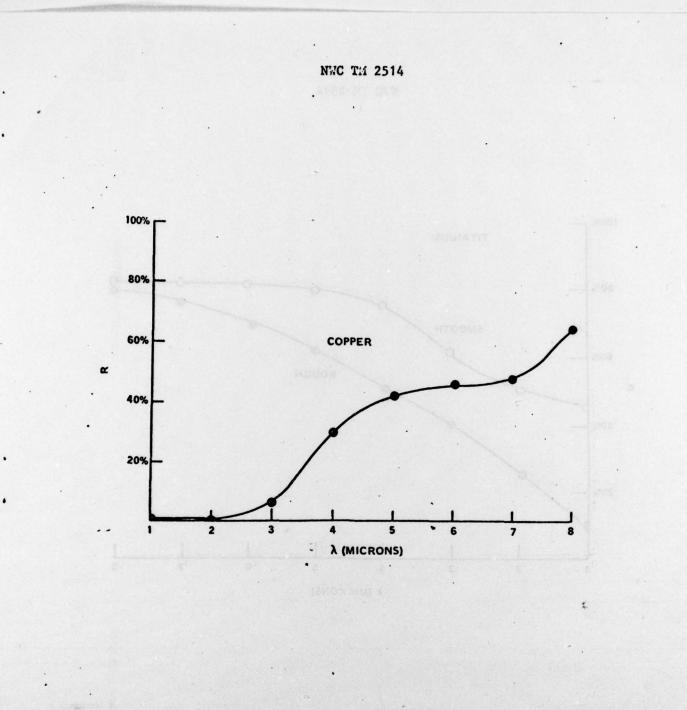




NUC TH 2514







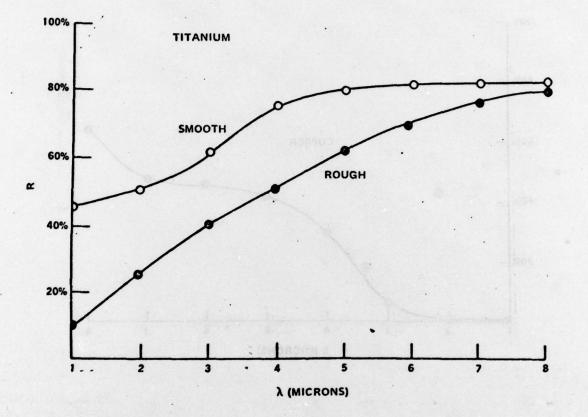
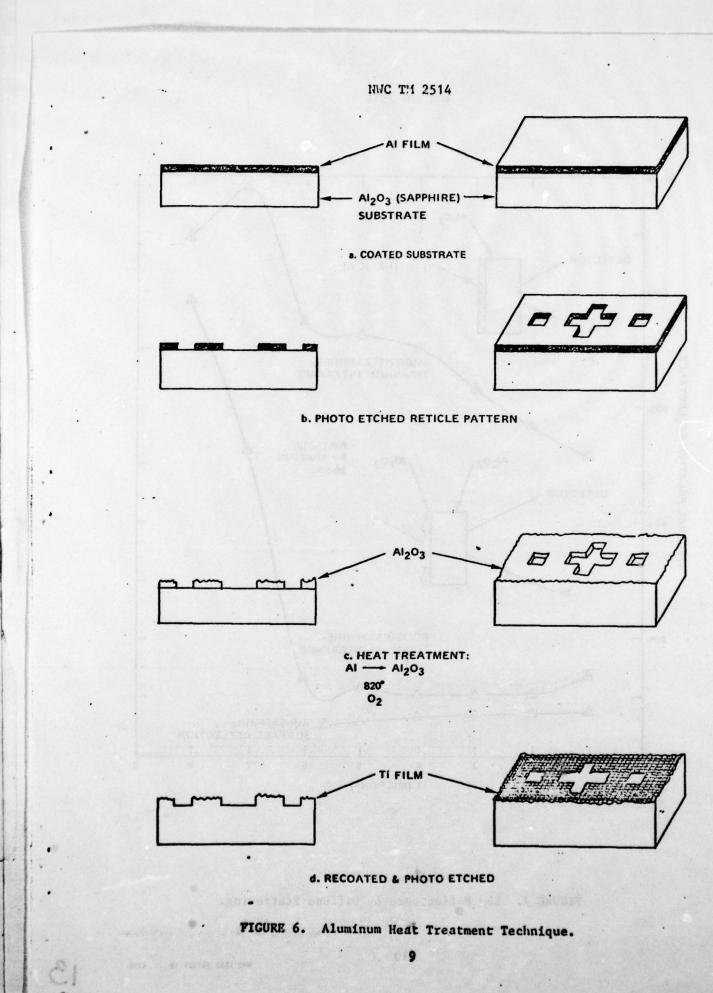


FIGURE 5. Reflectivity of Titanium on Quartz.

· . 4- 3301933 · ...

NVC TH 2514





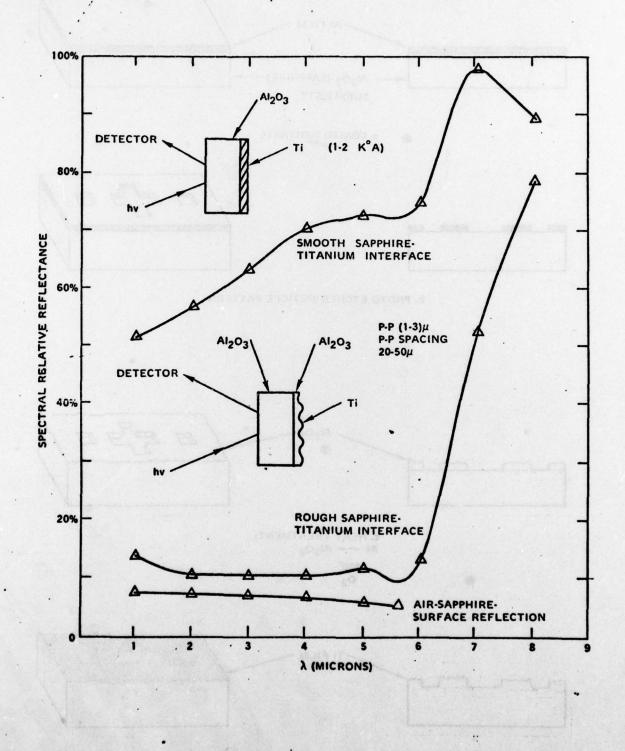


FIGURE 7. Low Reflectance by Diffuse Scattering.

10

A good the the strate of

OmnéA.

NIC 1253 (4/75) 19 4250